

Description

The RQ5E035ATTCL uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

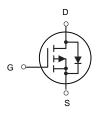
G SOT-23-3L (SOT-23F)

General Features

 $V_{DS} = -30V I_{D} = -4.2A$

 $R_{DS(ON)} < 54 m\Omega @ V_{GS} = 10V$

 $R_{DS(ON)}$ < 77m Ω @ V_{GS} =4.5V



P-Channel MOSFET

Application

Battery protection
Load switch
Uninterruptible power supply

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
RQ5E035ATTCL	SOT-23-3L(SOT-23F)	X1KX	3000

Absolute Maximum Ratings (T_A=25°C unless otherwise noted)

Symbol	Parameter	Limit	Unit
V _{DS}	Drain-Source Voltage	-30	V
V _G s	Gate-Source Voltage	±12	V
I _D	Drain Current-Continuous	-4.2	A
Ірм	Drain Current-Pulsed (Note 1)	-30	А
P _D	Maximum Power Dissipation	1.2	W
ТЈ,Тѕтс	Operating Junction and Storage Temperature Range	-55 To 150	$^{\circ}$
RеJA	Thermal Resistance,Junction-to-Ambient (Note 2)	104	°C/W

P-Channel Enhancement Mode MOSFET

Electrical Characteristics (T_A=25°C unless otherwise noted)

Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-24V,V _{GS} =0V	-	-	-1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±10V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =-250μA	-0.7	-1	-1.3	V
		V _{GS} =-10V, I _D =-4.2A	-	46	54	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-4A	-	58	77	mΩ
		V _{GS} =-2.5V, I _D =-1A		74	130	mΩ
Forward Transconductance	g FS	V _{DS} =-5V,I _D =-4.2A	-	10	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	- V _{DS} =-15V,V _{GS} =0V, - F=1.0MHz	-	880	-	PF
Output Capacitance	C _{oss}		-	105	-	PF
Reverse Transfer Capacitance	C _{rss}		-	65	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}	V_{DD} =-15V, I_{D} =-4.2A V_{GS} =-10V, R_{GEN} =6 Ω	-	7	-	nS
Turn-on Rise Time	t _r		-	3	-	nS
Turn-Off Delay Time	$t_{d(off)}$		-	30	-	nS
Turn-Off Fall Time	t _f		-	12	-	nS
Total Gate Charge	Qg	V _{DS} =-15V,I _D =-4.2A,V _{GS} =-4.5V	-	8.5	-	nC
Gate-Source Charge	Q _{gs}		-	1.8	-	nC
Gate-Drain Charge	Q_{gd}		-	2.7	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-4.2A	i	-	-1.2	V

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production



Typical Electrical and Thermal Characteristics

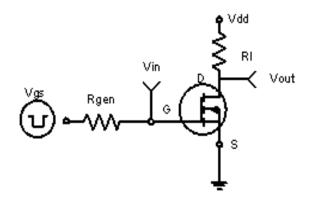
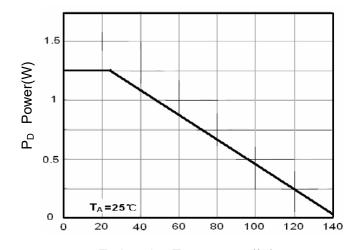
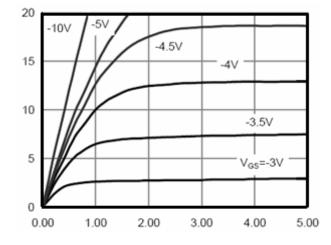


Figure 1:Switching Test Circuit



 T_J -Junction Temperature(${}^{\circ}$ C) Figure 3 Power Dissipation



Ip- Drain Current (A)

Vds Drain-Source Voltage (V) Figure 5 Output Characteristics

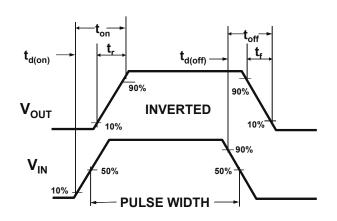
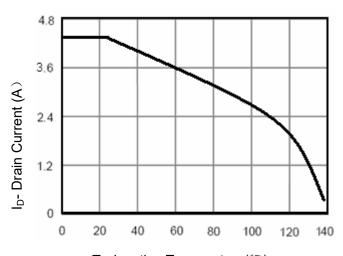
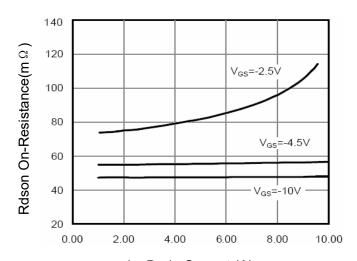


Figure 2:Switching Waveforms

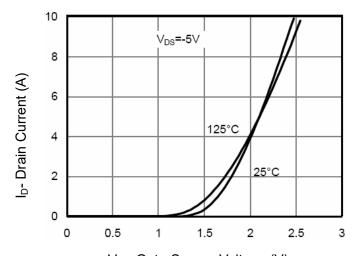


T_J-Junction Temperature(°C) Figure 4 Drain Current

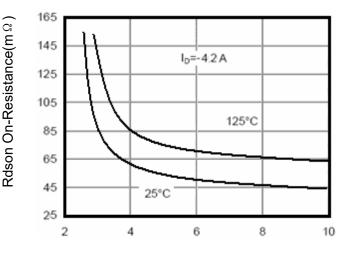


I_D- Drain Current (A) Figure 6 Drain-Source On-Resistance





Vgs Gate-Source Voltage (V) Figure 7 Transfer Characteristics



Vgs Gate-Source Voltage (V) Figure 9 Rdson vs Vgs

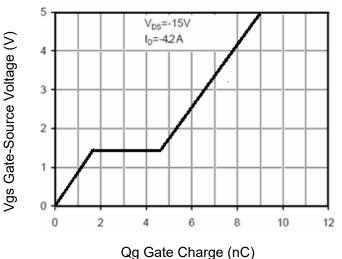


Figure 11 Gate Charge

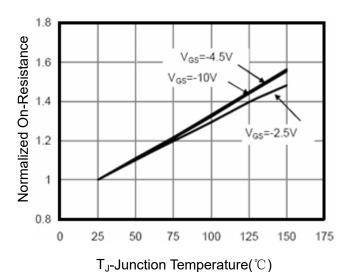
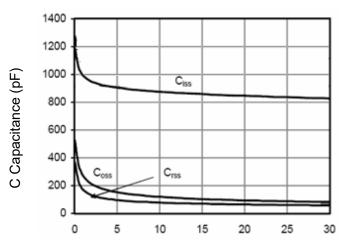


Figure 8 Drain-Source On-Resistance



Vds Drain-Source Voltage (V)
Figure 10 Capacitance vs Vds

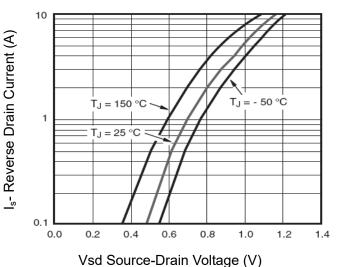
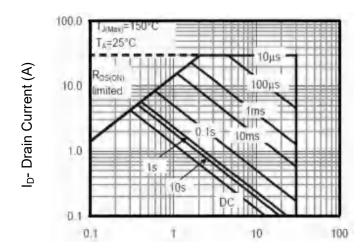


Figure 12 Source- Drain Diode Forward



Vds Drain-Source Voltage (V)
Figure 13 Safe Operation Area

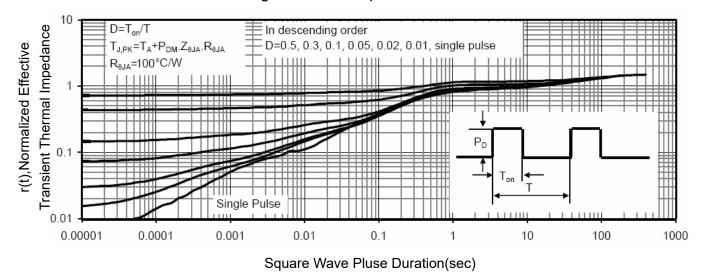
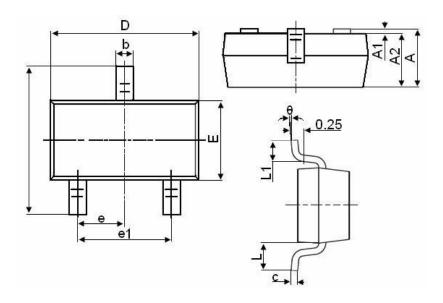


Figure 14 Normalized Maximum Transient Thermal Impedance

SOT-23-3L(SOT-23F)Package Information



Symbol	Dimensions in Millimeters			
	MIN.	MAX.		
А	1.050	1.250		
A1	0.000	0.100		
A2	1.050	1.150		
b	0.300	0.500		
С	0.100	0.200		
D	2.800	3.000		
E	1.500	1.700		
E1	2.650	2.950		
е		0.950TYP		
e1	1.800	2.000		
L	0.550REF			
L1	0.300	0.600		
θ	0°	8°		



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